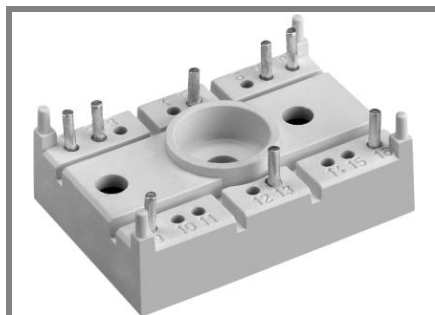


SK 100 KQ



SEMITOP® 2

Antiparallel Thyristor Module

SK 100 KQ

Preliminary Data

Features

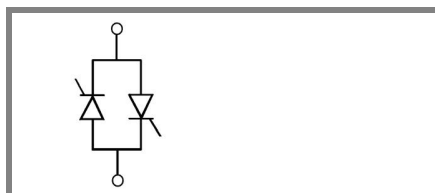
- Compact Design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications

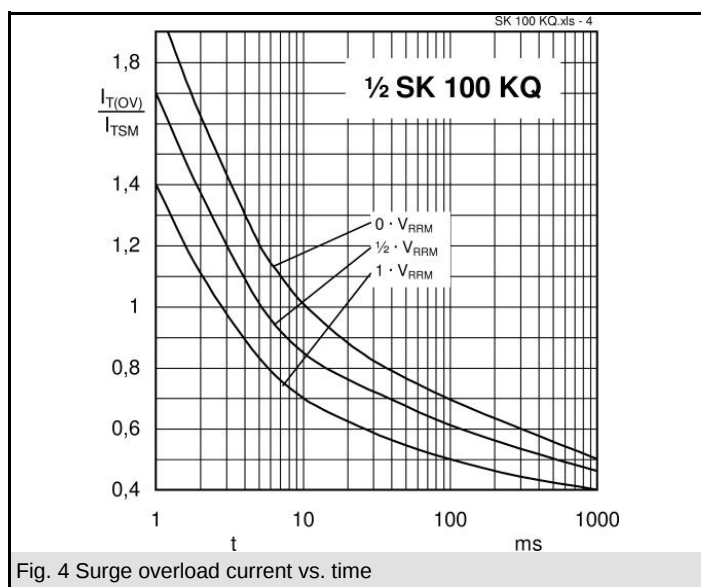
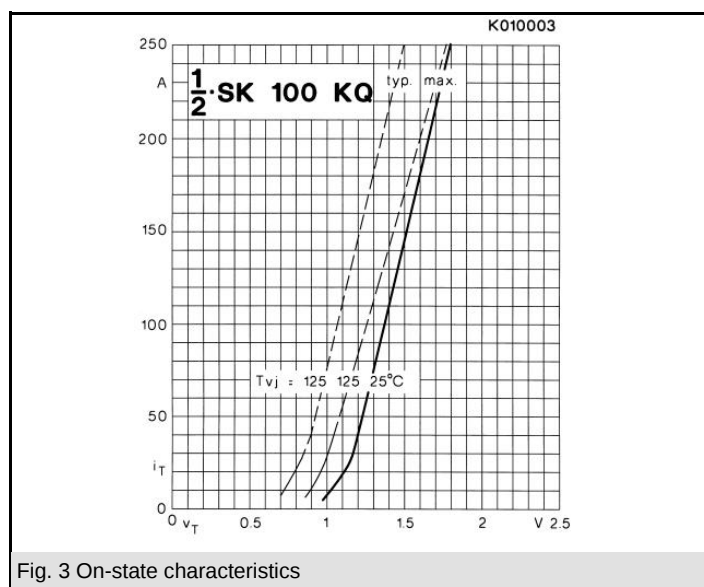
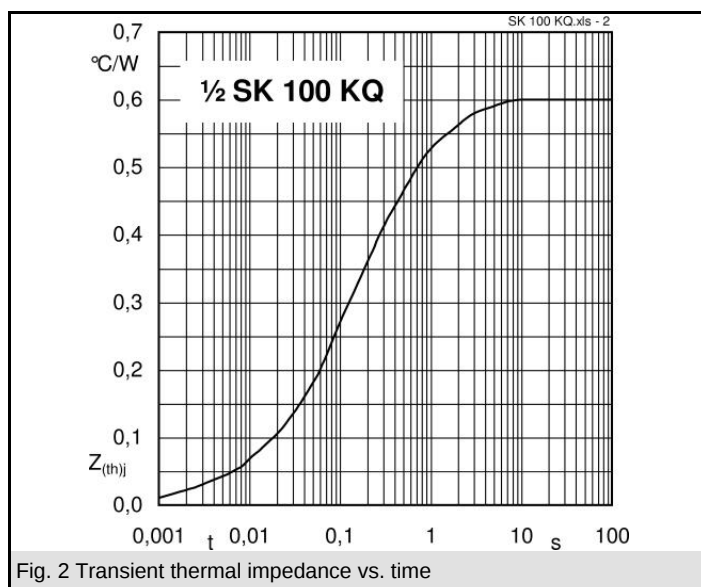
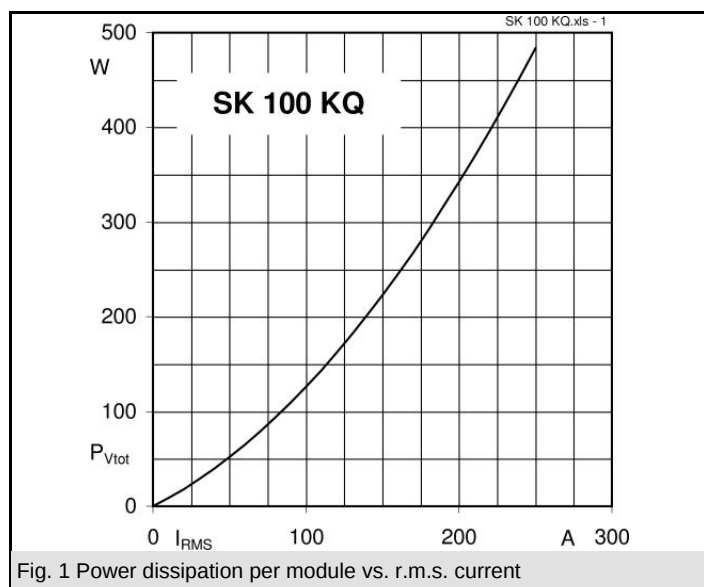
- Soft starters
- Light control (studios, theaters...)
- Temperature control

V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{RMS} = 101 \text{ A (full conduction)}$ ($T_s = 85^\circ \text{C}$)
900	800	SK 100 KQ 08
1300	1200	SK 100 KQ 12
1600	1700	SK 100 KQ 16

Symbol	Conditions	Values	Units
I_{RMS}	$W1C; \sin. 180^\circ; T_s = 100^\circ \text{C}$ $W1C; \sin. 180^\circ; T_s = 85^\circ \text{C}$	71 101	A A
I_{TSM}	$T_{vj} = 25^\circ \text{C}; 10 \text{ ms}$ $T_{vj} = 125^\circ \text{C}; 10 \text{ ms}$	1500 1350	A A
i^2t	$T_{vj} = 25^\circ \text{C}; 8,3...10 \text{ ms}$ $T_{vj} = 125^\circ \text{C}; 8,3...10 \text{ ms}$	11250 9100	A ² s A ² s
V_T $V_{T(TO)}$ r_T I_{DD}, I_{RD}	$T_{vj} = 25^\circ \text{C}, I_T = 200 \text{ A}$ $T_{vj} = 125^\circ \text{C}$ $T_{vj} = 125^\circ \text{C}$ $T_{vj} = 25^\circ \text{C}, V_{RD} = V_{RRM}$ $T_{vj} = 125^\circ \text{C}, V_{RD} = V_{RRM}$	max. 1,8 max. 0,9 max. 4,5 max. 1 max. 20	V V mΩ mA mA
t_{gd} t_{gr}	$T_{vj} = 25^\circ \text{C}, I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu\text{s}$ $V_D = 0,67 \cdot V_{DRM}$	1 2	μs μs
$(dv/dt)_{cr}$ $(di/dt)_{cr}$ t_q I_H I_L	$T_{vj} = 125^\circ \text{C}$ $T_{vj} = 125^\circ \text{C}; f = 50...60 \text{ Hz}$ $T_{vj} = 125^\circ \text{C}; \text{typ.}$ $T_{vj} = 25^\circ \text{C}; \text{typ.} / \text{max.}$ $T_{vj} = 25^\circ \text{C}; R_G = 33 \Omega; \text{typ.} / \text{max.}$	1000 100 80 100 / 200 200 / 500	V/μs A/μs μs mA mA
V_{GT} I_{GT} V_{GD} I_{GD}	$T_{vj} = 25^\circ \text{C}; \text{d.c.}$ $T_{vj} = 25^\circ \text{C}; \text{d.c.}$ $T_{vj} = 125^\circ \text{C}; \text{d.c.}$ $T_{vj} = 125^\circ \text{C}; \text{d.c.}$	min. 2 min. 100 max. 0,25 max. 5	V mA V mA
$R_{th(j-s)}$ $R_{th(f-s)}$ T_{vj} T_{stg} T_{solder}	cont. per thyristor sin 180° per thyristor cont. per W1C sin 180° per W1C terminals, 10s	0,6 0,63 0,3 0,315 -40 ... +125 -40 ... +125 260	K/W K/W K/W K/W °C °C °C
V_{isol} M_s M_t a m	a. c. 50 Hz; r.m.s.; 1 s / 1 min. Mounting torque to heatsink	3000 / 2500 2,0 19	V~ Nm Nm m/s ² g
Case	SEMITOP® 2	T 2	



KQ



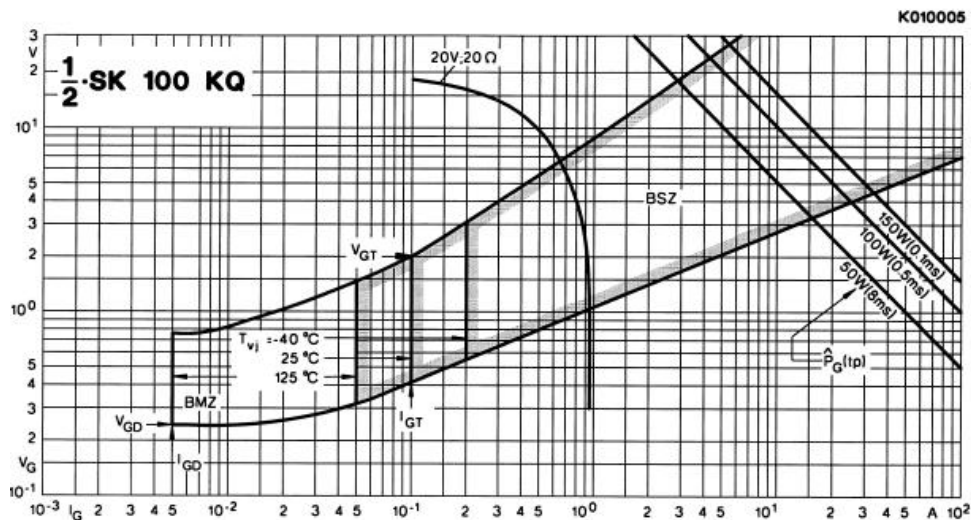
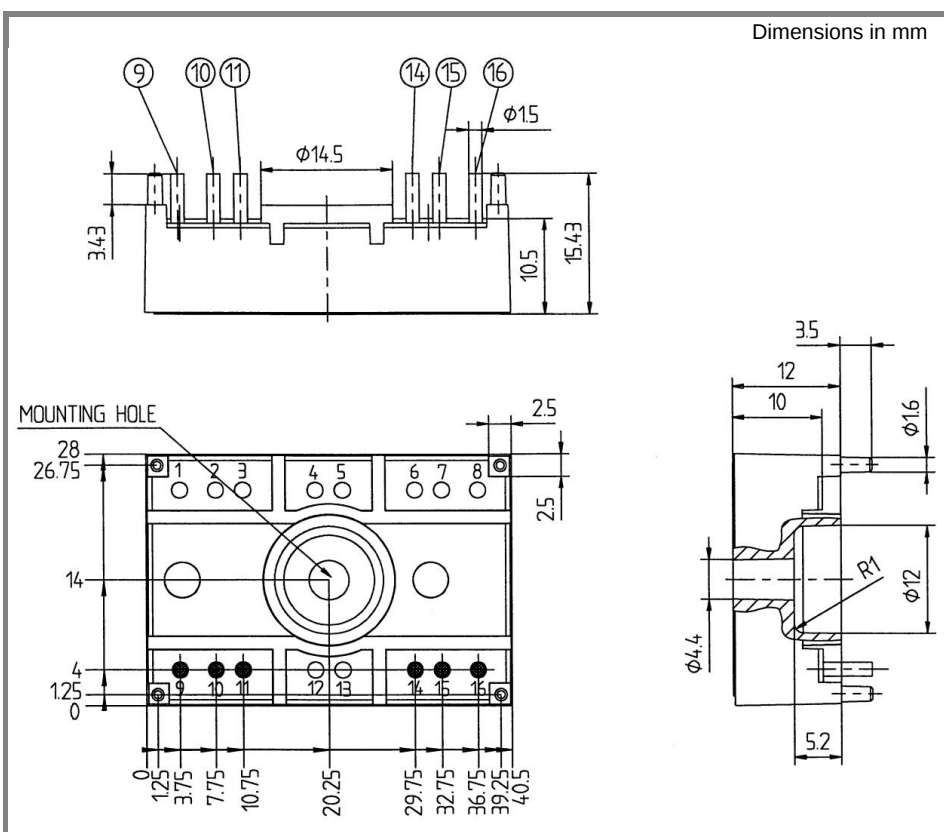
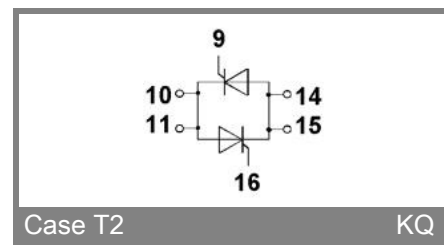


Fig. 5 Gate trigger characteristics



Case T 2 (Suggested hole diameter in the PCB for solder pins and mounting pins : 2mm)



Case T2

KQ

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.